

#### **Features**

- 2.5V to 5.5V Input Voltage
- 1.23V Feedback Voltage
- 1.2MHz Fixed Switching Frequency
- Internal 0.6A Switch Current Limit
- Internal Compensation
- Thermal Shutdown
- Available in a 5-pin SOT-23 package

#### **Applications**

- Camera Flash White LED
- Digital still cameras

PDA LED back light

### **General Description**

The HM1538B is a step-up converter. Its 1.23V feedback voltage reduces power loss and improves efficiency. Optimized operation frequency can meet the requirement of small LC filters value and low operation current with high efficiency. Internal soft start function can reduce the inrush current. Tiny package type provides the best solution for PCB space saving and total BOM cost.

### **Typical Application Circuit**

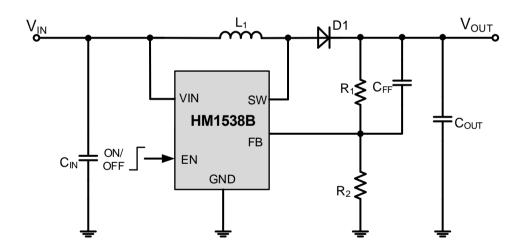
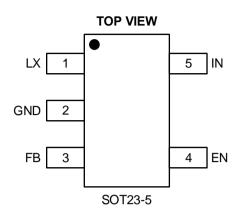


Figure 1. Basic Application Circuit



## **Package and Pin Description**



Top Marking: KF<u>YLL</u> (device code: KF, Y=year code, LL= lot number code)

Pin	Name	Function
1	LX	Power Switch Output. LX is the drain of the internal MOSFET switch. Connect the power inductor and output rectifier to LX. LX can swing between GND and 30V.
2	GND	Ground Pin
3	FB	Feedback Input. The FB voltage is 1.23V. Connect a resistor divider to FB.
4	EN	Regulator On/Off Control Input. A high input at EN turns on the converter, and a low input turns it off. When not used, connect EN to the input supply for automatic startup.
5	IN	Input Supply Pin. Must be locally bypassed.

### **Order Information**

Marking	Part No.	Model	Description	Package	MOQ
KF <u>YLL</u>	70390005	HM1538B	HM1538B Bias Driver, 2.5-5.5V, Vout 30V, 1.2MHz, SOT23-5	SOT23-5	3000PCS



## **Absolute Maximum Ratings**

Parameter	Absolute Maximum Ratings	Unit
$V_{IN}, V_{EN}$	-0.3 to 6	V
$V_{\rm SW}$	-0.3 to 30	V
All Other Pins	-0.3 to 6	V
Continuous Power Dissipation(T <sub>A</sub> =+25°C)	0.6	W
Junction Temperature	150	°C
Operating Temperature Range	-40 to 85	°C
Lead Temperature	260	°C
Storage Temperature	-65 to 150	°C
Thermal Resistance $\theta_{JA}$	250	°C/W
Thermal Resistance $\theta_{JC}$	130	°C /W

## **Recommended Operating Conditions**

Parameter	Recommended	Unit
Supply Voltage V <sub>IN</sub>	2.5 to 5.5	V
Output Voltage V <sub>OUT</sub>	V <sub>IN</sub> to 30	V
Operating Junction Temp.(T <sub>J</sub> )	-40 to 125	°C

## **Electrical Characteristics**

Parameter	Symbol	<b>Test Conditions</b>	Min	Тур	Max	Unit
Supply Current(Shutdown)	$I_{IN}$	V <sub>EN</sub> =0V		0.1	1	μΑ
Quiescent Current		V <sub>FB</sub> =1 V,switch		0.15	0.3	mA
SW Leakage		$V_{SW} = 20V$			1	μΑ
SW On Resistance				400	650	mΩ
Operating Input Voltage			2.5		5.5	V
Current Limit	I <sub>LIMIT</sub>	V <sub>IN</sub> = 4V,Duty cycle=50%		0.6		A
Oscillator Frequency	$f_{SW}$			1.2		MHz
Maximum Duty Cycle	$D_{MAX}$			90		%
Feedback Voltage	$V_{FB}$		1.21	1.23	1.25	mV
FB Input Bias Current		V <sub>FB</sub> =1V	-50	-10		nA
EN Threshold	V <sub>EN</sub>			1		V
Thermal Shutdown				160		°C
Supply Current(Shutdown)	$I_{IN}$	V <sub>EN</sub> =0V		0.1	1	μΑ



### **Application Information**

#### **Setting the Output Voltage**

The internal reference VREF is 1.2V (Typical). The output voltage is divided by a resistor divider, R1 and R2 to the FB pin. The output voltage is given by

$$R_2 = \frac{R_I}{V_{OUT} / V_{FB} - 1}$$

#### **Inductor Selection**

The recommended values of inductor are 2.2 to  $10\mu H$ . Small size and better efficiency are the major concerns for portable device, such as HM1538B used for mobile phone. The inductor should have low core loss at 1.2 MHz and low DCR for better efficiency. To avoid inductor saturation current rating should be considered.

#### **Capacitor Selection**

Input and output ceramic capacitors of  $22\mu F$  are recommended for HM1538B applications. For better voltage filtering, ceramic capacitors with low ESR are

recommended. X5R and X7R types are suitable because of their wider voltage and temperature ranges.

#### **Diode Selection**

Schottky diode is a good choice for HM1538B because of its low forward voltage drop and fast reverses recovery. Using Schottky diode can get better efficiency. The high speed rectification is also a good characteristic of Schottky diode for high switching frequency. Current rating of the diode must meet the root mean square of the peak current and output average current multiplication as following:

$$I_D(RMS) \approx \sqrt{I_{OUT} \times I_{PEAK}}$$

The diode's reverse breakdown voltage should be larger than the output voltage.

### **Layout Consideration**

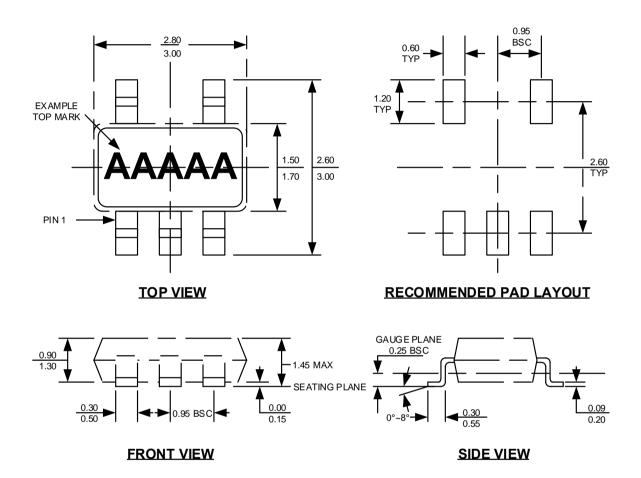
For best performance of the HM1538B, the following guidelines must be strictly followed.

- 1. Input and Output capacitors should be placed close to the IC and connected to ground plane to reduce noise coupling.
- 2. The GND should be connected to a strong ground plane for heat sinking and noise protection.
- 3. Keep the main current traces as possible as short and wide.
- 4. LX node of DC-DC converter is with high frequency voltage swing. It should be kept at a small area.
- 5. Place the feedback components as close as possible to the IC and keep away from the noisy devices.



### **Package Description**

#### SOT23-5



#### Note:

- 1. All dimensions are in millimeters.
- 2. Package length does not include mold flash, protrusion or gate burr.
- 3. Package width does not include flash or protrusion.
- 4. Lead coplanarity (bottom of leads after forming) shall be 0.10 millimeters max.
- 5. Pin 1 is lower left pin when reading top mark from left to right.